



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

George Jonathan KLUTH, et al.

Serial No.: 10/071,207

Group Art Unit: 2811

Filed: February 11, 2002 Examiner: GUERRERO, Maria F.

METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE WITH For:

SUPERSATURATED SOURCE/DRAIN EXTENSIONS AND METAL SILICIDE

**CONTACTS** 

## **RESPONSE TO RESTRICTION REQUIREMENT**

Commissioner for Patents Washington, DC 20231

Sir:

Noting the Office Action of December 31, 2002 wherein restriction has been required, the Contract of the Contr Applicant(s) hereby elect Group I (claims 1-18) with traverse for prosecution in the above and a superstance of the superstance identified application.

To the extent necessary, a petition for an extension of time under 37 C.F.R. 1.136 is hereby made. Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

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**Date: January 14, 2003** 

**CENTER 2800** 

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